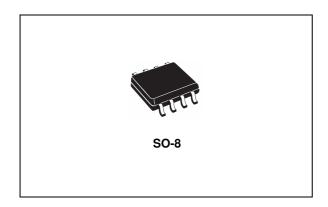


0.5 A max constant current LED driver

Datasheet - production data



Features

- Up to 40 V input voltage
- · Less than 0.5 V voltage overhead
- Up to 0.5 A output current
- PWM dimming pin
- Shutdown pin
- LED disconnection diagnostic

Applications

- LED constant current supplying for varying input voltages
- Low voltage lighting
- · Small appliances LED lighting

Description

The STCS05A is a BiCMOS constant current source designed to provide a precise constant current starting from a varying input voltage source. The main target is to replace discrete components solution for driving LEDs in low voltage applications such as 5 V, 12 V or 24 V giving benefits in terms of precision, integration and reliability.

The current is set with external resistor up to 0.5 A with a \pm 10 % precision; a dedicated pin allows implementing PWM dimming. An external capacitor allows setting the slope for the current rise from tens of microseconds to tens of milliseconds allowing reduction of EMI.

An open-drain pin output provides information on load disconnection condition.

Table 1. Device summary

Order code	Package	Packing
STCS05ADR	SO-8	2500 parts per reel

Contents STCS05A

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1	App	pplication diagram					
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1 Application diagram

Figure 1. Typical application diagram for 0.5 A LED current

Pin configuration STCS05A

2 Pin configuration

Figure 2. Pin connections (top view)

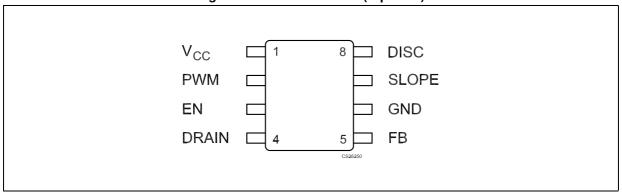


Table 2. Pin description

Pin n°	Symbol	Note
1	V_{CC}	Supply voltage
2	PWM	PWM dimming input
3	EN	Shutdown pin
4	DRAIN	Internal N-MOSFET drain
5	FB	Feedback input. The control loop regulates the current in such a way that the average voltage at the FB input is 100 mV (nominal). The cathode of the LED and a resistor to ground to set the LED current should be connected at this point.
6	GND	Ground
7	SLOPE	Capacitor for slope control
8	DISC	Load disconnection flag (open drain)

STCS05A Maximum ratings

3 Maximum ratings

Table 3. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V _{CC}	DC supply voltage	-0.3 to +45	V
DRAIN	Drain pin	-0.3 to +45	V
PWM, EN, DISC	Logic pins	-0.3 to + V _{CC} + 0.3	V
SLOPE, FB	Configuration pins	-0.3 to + 3.3	V
ESD	Human body model (all pins)	± 2	kV
Power Dissipation	SO-8 T _A = 25°C ⁽¹⁾	1.25	W
T _J	Junction temperature	-40 to 150	°C
T _{STG}	Storage temperature range	-55 to 150	°C

^{1.} See Figure 16 for details of max power dissipation for ambient temperature higher than 25 °C

Note:

Absolute maximum ratings are those values beyond which damage to the device may occur. Functional operation under these conditions is not implied.

Table 4. Thermal data

Symbol	Parameter	SO-8	Unit
R _{thJC}	Thermal resistance junction-case	20	°C/W
R _{thJA}	Thermal resistance junction-ambient (1)	100	°C/W

^{1.} This value depends from thermal design of PCB on which the device is mounted.

Electrical characteristics STCS05A

4 Electrical characteristics

 $\begin{array}{l} \textbf{Table 5. Electrical characteristics} \; (V_{CC} = 12 \; V; \; I_O = 100 \; \text{mA}; \; T_J = \text{-}40 \; ^{\circ}\text{C} \; \text{to} \; 125 \; ^{\circ}\text{C}; \; V_{DRAIN} = 1 \; V; \\ C_{DRAIN} = 1 \; \mu\text{F}; \; C_{BYP} = 100 \; \text{nF} \; \text{typical values are at} \; T_A = 25 \; ^{\circ}\text{C}, \; \text{unless otherwise specified}) \end{array}$

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit	
V _{CC}	Supply voltage range		4.5		40	V	
	Output current range		1		500	mA	
I _O	Output current	$R_{FB} = 0.2 \Omega$		500		mA	
	Regulation (percentage with respect to V _{CC} = 12 V)	$V_{CC} = 4.5 \text{ to } 40 \text{ V},$ $I_{O} = 100 \text{ mA}; V_{DRAIN} = 1 \text{ V}$	-1		+1	%	
V _{FB}	Feedback Voltage	I _O = 0 to 0.5 A	90	100	110	mV	
		On Mode		450	750		
I _{CC}	Quiescent current (Measured on V _{CC} pin)	Shutdown Mode; V _{CC} = 5 to 12 V			1	μΑ	
	- 00 P** 7	Shutdown Mode; V _{CC} = 12 to 40 V			3		
V .	Dropout voltage (V to CND)	I _O = 100 mA		0.12	0.16	V	
V _{DROP}	Dropout voltage (V _{DRAIN} to GND)	I _O = 0.5 A		0.58	0.9	V	
LEAK _{DRAIN}	Drain leakage current	Shutdown; V _{DRAIN} = 40 V			10	μΑ	
T _R /T _F	Rise/Fall time of the current on PWM transition	C _{SLOPE} = 10 nF, T _J = -40 °C to 105 °C		800		μs	
т	Delay on PWM signal (see	V_{PWM} rising, $V_{CC} = 12 \text{ V}$ $C_{SLOPE} = \text{floating}$		3			
T _D	Figure 3)	V _{PWM} falling, V _{CC} = 12 V C _{SLOPE} = floating		1.2		μs	
	Low level voltage	I _{SINK} = 5 mA		0.2	0.5	V	
DISC	Leakage current	V _{DISC} = 5 V			1	μΑ	
DISC	Load disconnection threshold	DISC Turn-ON		75		mV	
	(V _{DRAIN} -GND)	DISC Turn-OFF		110		111 V	
Thermal	Shutdown temperature			155		°C	
Protection	Hysteresis			25		C	
Logic input	s (PWM and EN)						
V _L	Input low level				0.4	٧	
V _H	Input high level		1.2			V	
	EN, PWM leakage current	V _{EN} = 5 V; V _{PWM} = 5 V			2		
	EN input leakage current	V _{EN} = 40 V			60	μΑ	
	PWM input leakage current	V _{PWM} = 40 V			120]	

Note: All devices 100 % production tested at $T_A = 25$ °C. Limits over the operating temperature range are guaranteed by design.

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STCS05A Timing

5 Timing

Figure 3. PWM and output current timing

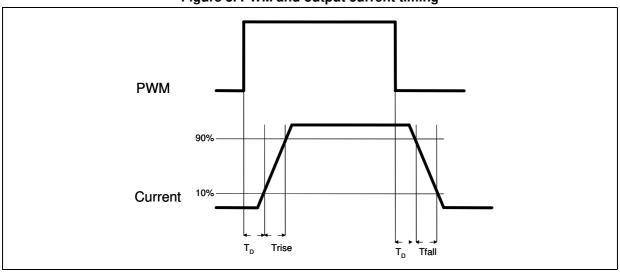
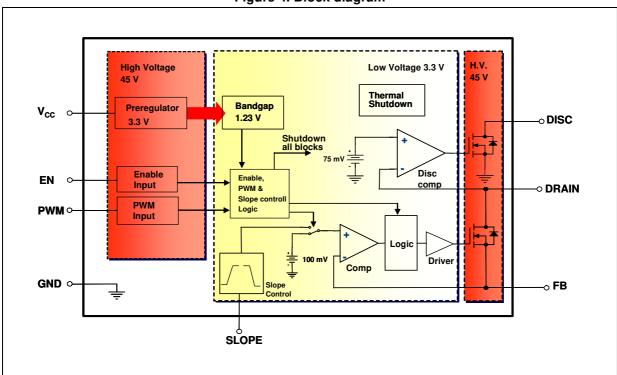
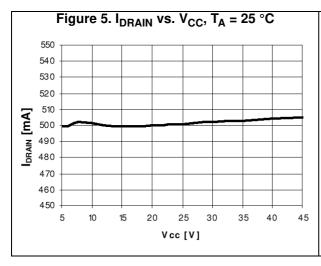
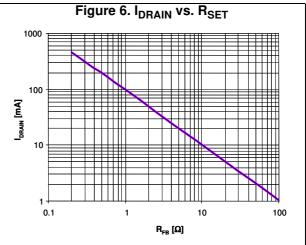


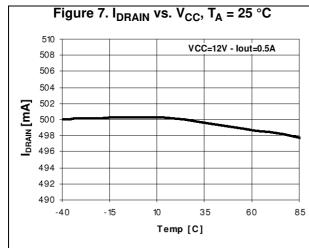
Figure 4. Block diagram

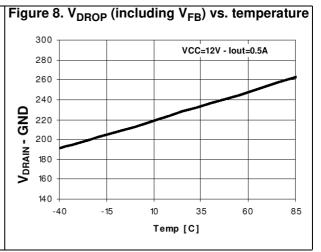


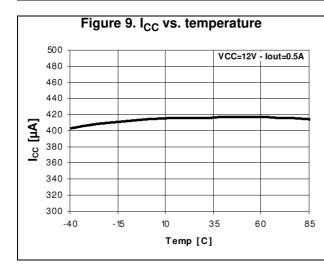
6 Typical performance characteristics

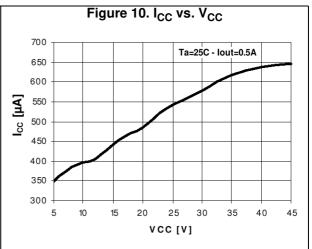






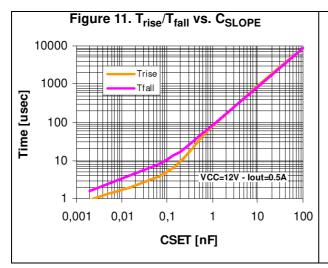


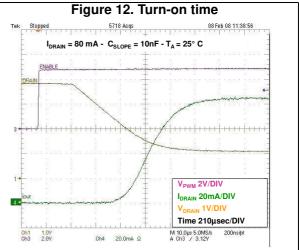


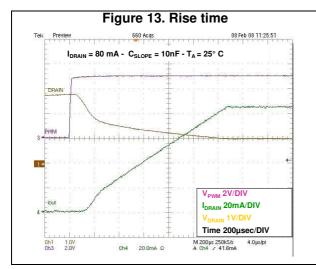


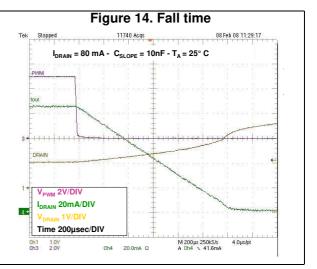
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Detail description STCS05A

7 Detail description

The STCS05A is a BiCMOS constant current source designed to provide a precise constant current starting from a varying input voltage source. The main target is to replace discrete components solution for driving LEDs in low voltage applications such as 5 V, 12 V or 24 V giving benefits in terms of precision, integration and reliability.

7.1 Current setting

The current is set with an external sensing resistor connected to the FB pin. The feedback voltage is 100 mV, then a low resistor value can be chosen reducing power dissipation. A value between 1 mA and 500 mA can be set according to the resistor value, the resulting output current has a tolerance of \pm 10 %.

For instance, should one need a 350 mA LEDs current, R_{F} should be selected according to the following equation:

 $R_F = V_{FB} / I_{LEDs} = 100 \text{ mV} / 350 \text{ mA} = 284 \text{ m}\Omega$

7.2 Enable

When the enable pin is low the device completely off thus reducing current consumption to less than 1 μ A. When in shutdown mode, the internal main switch is off.

7.3 PWM dimming

The PWM input allows implementing PWM dimming on the LED current; when the PWM input is high the main switch will be on and vice versa. A typical frequency range for the input is from few Hertz to 50 kHz. The maximum dimming frequency is limited by the minimum rise/fall time of the current (obtained with $C_{SLOPE} = 0$) which is around 4 μ s each. Above 50 kHz the current waveforms starts assuming a triangular shape.

While the PWM input is switching, the overall circuitry remains on, this is needed in order to implement two important features: short delay time and controlled slope for the current.

Since the PWM pin is controlling just the main switch, the overall circuitry is always on and it is able to control the delay time between the PWM input signal and the output current in the range of few μ s, this is important to implement synchronization among several light LED sources.

The rise and fall slope of the current is controlled by the C_{SLOPE} capacitor. The rise and fall time are linear dependent from the C_{SLOPE} capacitor value (see graph in typical characteristics). A controlled rise time has two main benefits: reducing EMI noise and avoid current spike at turn on.

When C_{SLOPE} is left floating, the internal switch is turned on at maximum speed, in this condition an overshoot can be present on the LED current before the system goes into regulation.

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STCS05A Detail description

7.4 Diagnostic

When STCS05A is in on mode (EN is high), the device is able to detect disconnection or fail of the LED string monitoring V_{DRAIN} pin. If V_{DRAIN} is lower than 75 mV the DISC pin is pulled low regardless the PWM pin status. This information can be used by the system to inform that some problem happens in the LEDs.



8 Application information

8.1 Reverse polarity protection

STCS05A must be protected from reverse connection of the supply voltage. Since the current sunk from V_{CC} pin is in the range of 450 μ A a small diode connected to V_{CC} is able to protect the chip. Care must be taken for the whole application circuit, especially for the LEDs, in fact, in case a negative voltage is applied between V_{IN} and GND, a negative voltage will be applied to the LED string that must have a total breakdown voltage higher than the negative applied voltage in order to avoid any damage.

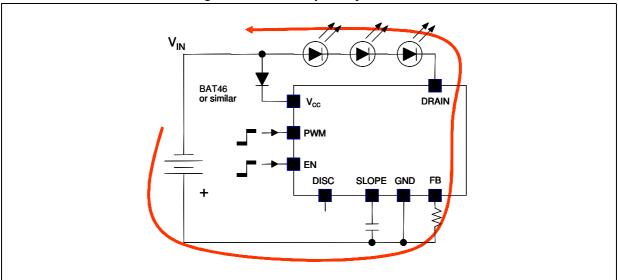


Figure 15. Reverse polarity condition

8.2 Thermal considerations

The STCS05A is able to control a LED current up to 500 mA and able to sustain a voltage on the drain pin up to 40 V. Those operating conditions are however limited by thermal constraints, the thermal resistances shown in the thermal data section is the typical ones.

The power dissipation in the device can be calculated as follow:

$$P_D = (V_{DRAIN} - V_{FB}) \times I_{LED} + (V_{CC} \times I_{CC})$$

basing on this and on the thermal resistance and ambient temperature, the junction temperature can be calculated as:

$$T_{J} = R_{th,JA} \times P_D + T_A$$

A typical application could be:

- Input voltage: 12 V;
- 3 white LEDs with an typical $V_F = 3.6 \text{ V}$;
- LEDs current: 350 mA;
- Package: SO-8;

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$$- T_A = 50 \, ^{\circ}C;$$

In this case $V_{DRAIN} = 12 - 3 \times 3.6 = 1.2 \text{ V}$

$$P_D = (1.2 - 0.1) \times 0.35 + 12 \times 0.5 \times 10^{-3} = 0.385 + 6 \times 10^{-3} = 391 \text{ mW}$$

The junction temperature will be:

$$T_J = 100 \times 0.391 + 50 = 89 \, ^{\circ}C$$

For a correct operation of the chip, in this example the ambient temperature must not exceed about 110 $^{\circ}$ C.

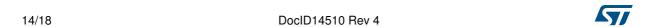
The following pictures show the maximum power dissipation according to the ambient temperature:

1.40 R_{thJA} = 100 [°C/W] 1.20 1.00 0.80 0.60 $\mathsf{P}_{\mathsf{DMAX}} = (\mathsf{T}_{\mathsf{JMAX}} \text{-} \mathsf{T}_{\mathsf{A}}) / \mathsf{R}_{\mathsf{thJA}}$ 0.40 0.20 45 55 65 75 85 25 35 95 105 115 125 [°C]

Figure 16. Maximum power dissipation vs T_A for SO-8

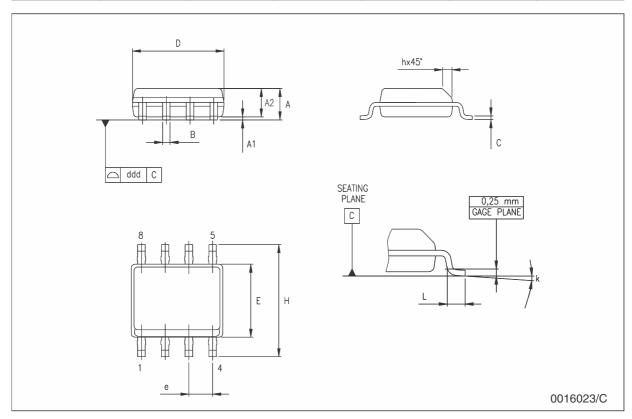
9 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: www.st.com. ECOPACK[®] is an ST trademark.



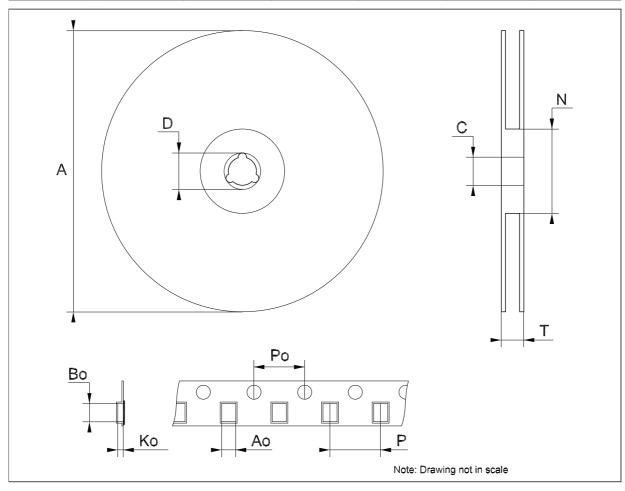
SO-8 mechanical data

Dim.		mm.			inch.		
Dilli.	Min.	Тур.	Max.	Min.	Тур.	Max.	
А	1.35		1.75	0.053		0.069	
A1	0.10		0.25	0.04		0.010	
A2	1.10		1.65	0.043		0.065	
В	0.33		0.51	0.013		0.020	
С	0.19		0.25	0.007		0.010	
D	4.80		5.00	0.189		0.197	
E	3.80		4.00	0.150		0.157	
е		1.27			0.050		
Н	5.80		6.20	0.228		0.244	
h	0.25		0.50	0.010		0.020	
L	0.40		1.27	0.016		0.050	
k			8° (n	nax.)	•	•	
ddd			0.1			0.04	



Tape & reel SO-8 med	chanical data
----------------------	---------------

Dim.	mm.			inch.		
Dilli.	Min.	Тур.	Max.	Min.	Тур.	Max.
А			330			12.992
С	12.8		13.2	0.504		0.519
D	20.2			0.795		
N	60			2.362		
Т			22.4			0.882
Ao	8.1		8.5	0.319		0.335
Во	5.5		5.9	0.216		0.232
Ko	2.1		2.3	0.082		0.090
Po	3.9		4.1	0.153		0.161
Р	7.9		8.1	0.311		0.319



STCS05A Revision history

10 Revision history

Table 6. Document revision history

Date	Revision	Changes	
04-Mar-2008	1	Initial release.	
02-Jul-2008	2	Modified: Table 5 on page 6.	
20-Jan-2022	3	Updated: Applications on the cover page.	
21-Apr-2022	4	Updated: Power dissipation value in <i>Table 3</i> and <i>Section 8.2</i> .	

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